

# Northumbria Research Link

Citation: Li, Chunchun, Yin, Changzhi, Deng, Ming, Shu, Longlong and Khaliq, Jibran (2020) Tunable microwave dielectric properties in SrO-V2O5 system through compositional modulation. Journal of the American Ceramic Society, 103 (4). pp. 2315-2321. ISSN 0002-7820

Published by: Wiley-Blackwell

URL: <https://doi.org/10.1111/jace.16955> <<https://doi.org/10.1111/jace.16955>>

This version was downloaded from Northumbria Research Link:  
<http://nrl.northumbria.ac.uk/id/eprint/41995/>

Northumbria University has developed Northumbria Research Link (NRL) to enable users to access the University's research output. Copyright © and moral rights for items on NRL are retained by the individual author(s) and/or other copyright owners. Single copies of full items can be reproduced, displayed or performed, and given to third parties in any format or medium for personal research or study, educational, or not-for-profit purposes without prior permission or charge, provided the authors, title and full bibliographic details are given, as well as a hyperlink and/or URL to the original metadata page. The content must not be changed in any way. Full items must not be sold commercially in any format or medium without formal permission of the copyright holder. The full policy is available online: <http://nrl.northumbria.ac.uk/policies.html>

This document may differ from the final, published version of the research and has been made available online in accordance with publisher policies. To read and/or cite from the published version of the research, please visit the publisher's website (a subscription may be required.)



**Northumbria**  
**University**  
NEWCASTLE



**Tunable microwave dielectric properties in SrO-V2O5 system through compositional modulation**

Journal:	<i>Journal of the American Ceramic Society</i>
Manuscript ID	JACERS-44698.R2
Manuscript Type:	Rapid Communication
Date Submitted by the Author:	n/a
Complete List of Authors:	<p>Li, Chunchun; Guilin University of Technology, College of Information Science and Engineering; Guilin University of Technology, Key laboratory of New Processing Technology for Nonferrous Metal and Materials Ministry of Education</p> <p>Yin, Changzhi; State Key Laboratory Breeding Base of Nonferrous metals and specific Materials Processing, Guangxi universities key laboratory of non-ferrous metal oxide electronic functional materials and devices, College of Material Science and Engineering, Guilin University of Technology</p> <p>Deng, Ming; Guilin University of Technology, College of Information Science and Engineering</p> <p>Shu, Longlong; Nanchang University, School of Materials Science and Engineering</p> <p>Khaliq, Jibrán; University of Northumbria at Newcastle</p>
Keywords:	ceramic matrix composites, dielectric materials/properties, LTCC, microwaves
Author-supplied Keyword: If there is one additional keyword you would like to include that was not on the list, please add it below::	

SCHOLARONE™  
Manuscripts

# Tunable microwave dielectric properties in SrO-V<sub>2</sub>O<sub>5</sub> system through compositional modulation

Chunchun Li<sup>1,2\*</sup>, Changzhi Yin<sup>2</sup>, Ming Deng<sup>1</sup>, Longlong Shu<sup>3</sup>, Jibran Khaliq<sup>4\*\*</sup>

<sup>1</sup> College of Information Science and Engineering, Guilin University of Technology, Guilin, 541004, China

<sup>2</sup> State Key Laboratory Breeding Base of Nonferrous metals and specific Materials Processing, Guangxi universities key laboratory of non-ferrous metal oxide electronic functional materials and devices, College of Material Science and Engineering, Guilin University of Technology, Guilin, 541004, China

<sup>3</sup> School of Materials Science and Engineering, Nanchang University, Nanchang 330031, People's Republic of China

<sup>4</sup> Department of Mechanical and Construction Engineering, Faculty of Engineering and Environment, Northumbria University at Newcastle, NE1 8ST, UK

## Abstract

Adjustment on resonance frequency stability against the sintering temperature of Sr<sub>3</sub>V<sub>2</sub>O<sub>8</sub> was realized through adjusting the Sr:V mole ratio. Effects of Sr:V ratio on sintering behavior and dielectric properties of Sr<sub>3</sub>V<sub>2</sub>O<sub>8</sub> were studied. The sintering temperature was successfully reduced to 950 °C from 1150 °C. With increasing vanadium content, both relative permittivity and quality factor decreased, while the temperature coefficient of resonance frequency shifted from positive to negative values. Especially, a near-zero  $\tau_f$  of -1.1 ppm/°C along with a low permittivity ( $\epsilon_r$ ) of 9.8 and a quality factor  $Q \times f$  of 24,120 GHz was successfully achieved in Sr<sub>3-y</sub>V<sub>2</sub>O<sub>8-y</sub> ceramic ( $y = 0.6$ , sintered at 950 °C). The wide compositional and processing adjustment window, favorable dielectric performances, and good chemical compatibility with silver render Sr<sub>3-y</sub>V<sub>2</sub>O<sub>8-y</sub> ceramics potential candidates in multilayer electronic devices.

**Keywords:** Ceramics; Dielectric properties; Microwave resonance; Composite

---

\* Corresponding Author, [lichunchun2003@126.com](mailto:lichunchun2003@126.com), \*\*[Jibran.khaliq@northumbria.ac.uk](mailto:Jibran.khaliq@northumbria.ac.uk)

ceramics

## 1. Introduction

The developments of commercial wireless technologies, especially the fifth-generation (5G) telecommunication, Internet of Things (IoTs) and military radar systems, have expanded the operating frequency to the millimeter-wave range. This new technological paradigm brings out the increasing demands of high-speed signal propagation at high-frequency regions [1-4]. For ceramics used as substrates, low permittivity ( $\epsilon_r < 15$ ) is required for fast signal transmission and minimizing the crosscoupling between the substrates and the conductors [5-7]. Other properties such as high quality factors ( $Q \times f$ ) and near-zero temperature coefficient of resonant frequency ( $\tau_f$ ) are also essential for practical applications [8-10]. To date, a large number of dielectric materials have been reported, however, only a few numbers of available options could meet the combination requirements simultaneously. Thus, developing new materials with desired microwave dielectric properties is still a challenge.

To reduce the permittivity, two possible approaches have been proposed in the literatures [11, 12], one of which is to decrease the number of dipoles while the second is to lower the dipole strength. The former method involves lowering the density through introduction of porosity. This however sacrifices mechanical strength and thermal conductivity while increasing dielectric loss. Lowering the dipole strength is more desirable through introducing covalent bond. To date, a number of promising low-permittivity materials ( $\epsilon_r < 15$ ) have been reported. All of those materials have

1  
2  
3  
4 tetrahedral unit cell, such as borates, silicates, phosphates, and vanadates [3, 12-14].  
5  
6 Amongst them, vanadates have attracted considerable attention due to cheap raw  
7  
8 materials, simple synthetic process, and good microwave dielectric properties [15-18].  
9  
10 For example, alkaline earth orthovanadates,  $M_3(VO_4)_2$  ( $M = Mg, Ba, Sr$ ) are promising  
11  
12 candidates with low dielectric loss and low- $\epsilon_r$  for high-frequency application [17-19].  
13  
14  $Mg_3(VO_4)_2$  sintered at 950 °C possesses  $\epsilon_r = 9.3$ ,  $Q \times f = 65,540$  GHz and  $\tau_f = -89.5$   
15  
16 ppm/°C [19], and  $Ba_3(VO_4)_2$  exhibited good dielectric performances with  $\epsilon_r \sim 11.3$ ,  $Q \times f$   
17  
18  $\sim 62,347$  GHz and  $\tau_f \sim 28.8$  ppm/°C when sintered at 1400 °C [20]. In our previous  
19  
20 work,  $Ba_{3-x}Sr_x(VO_4)_2$  solid solution series were reported to have promising microwave  
21  
22 dielectric properties with  $\epsilon_r = 11-16$ ,  $Q \times f = 40,000-66,000$ GHz, and  $\tau_f = 20-70$  ppm/°C  
23  
24 [21]. Particularly,  $Sr_3(VO_4)_2$  has the lowest densification temperature ( $\sim 1150$  °C) along  
25  
26 with a combination of promising dielectric performances with a high quality factor of  
27  
28 44,340 GHz and a low dielectric permittivity of 12.2. The high sintering temperature  
29  
30 ( $>1000$  °C) and relatively large positive  $\tau_f$  value ( $\sim +63.5$  ppm/°C), however, still limits  
31  
32 its potential utilization in low temperature cofired ceramics (LTCC) application in  
33  
34 which the ceramic layers should be cofired with the inner electrodes (generally silver)  
35  
36 [22]. Thus, reduction in sintering temperature to below the melting temperature of silver  
37  
38 (961 °C) and tailoring  $\tau_f$  to near-zero is necessary for  $M_3(VO_4)_2$  [23-25].  
39  
40  
41  
42  
43  
44  
45  
46  
47  
48  
49  
50

51 According to the binary phase diagram of SrO-V<sub>2</sub>O<sub>5</sub>, there are two stable phases  
52  
53  $Sr_2V_2O_7$  with triclinic structure and  $Sr_3(VO_4)_2$  and both of the phases can coexist [26].  
54  
55 Importantly, one of the advantages of  $Sr_2V_2O_7$  is to have a negative  $\tau_f$  value  $\sim -34.8$   
56  
57 ppm/°C which can behave as a  $\tau_f$  compensator for  $Sr_3(VO_4)_2$ . Both phases can coexist  
58  
59  
60

1  
2  
3  
4 by adjusting Sr:V mole ratio in the binary SrO-V<sub>2</sub>O<sub>5</sub> system to complement each other  
5  
6 [27]. Based on this rationale, this paper proposed the formation of the second phase to  
7  
8 compensate  $\tau_f$  value in-situ by compositional modification, a reliable and simple  
9  
10 method, which was validated and verified in Sr<sub>3-y</sub>V<sub>2</sub>O<sub>8-y</sub> ( $0 \leq y \leq 1$ ) ceramics system.  
11  
12 A series of different Sr:V ratio compounds in the Sr<sub>3-y</sub>V<sub>2</sub>O<sub>8-y</sub> ( $y = 0.2-0.8$ ) system were  
13  
14 prepared and characterized for the relationships between the phase composition and  
15  
16 microwave dielectric properties.  
17  
18  
19  
20  
21

## 22 **2. Experimental Procedure**

### 23 *2.1 Sample preparation*

24  
25  
26 Sr<sub>3-y</sub>V<sub>2</sub>O<sub>8-y</sub> ( $y = 0.2, 0.4, 0.6, 0.8$ ) ceramics were prepared via conventional solid-  
27  
28 state method from individual reagent-grade oxide powders: SrCO<sub>3</sub>, (> 99.95%, Guo-  
29  
30 Yao Co., Ltd Shanghai, China) and NH<sub>4</sub>VO<sub>3</sub> (> 99.9%, Guo-Yao Co., Ltd Shanghai,  
31  
32 China). The powders were weighted according to the stoichiometric composition of Sr<sub>3-  
33  
34 y</sub>V<sub>2</sub>O<sub>8-y</sub>, and ball milled in alcohol medium for 6 h in nylon battle with zirconia balls.  
35  
36 After drying the slurry at 120 °C for 1 h, the obtained powders were calcined at 850 °C  
37  
38 for 6 h in air. The calcined powders were ball-milled again for 6 h followed by cold-  
39  
40 pressing into cylinders (10 mm in diameter and 6 mm in thickness) in a steel die under  
41  
42 a pressure of 200 MPa with polyvinyl alcohol (PVA, 10 vol.%) as s binder. The Sr<sub>3-  
43  
44 y</sub>V<sub>2</sub>O<sub>8-y</sub> pellets were sintering at in the range of 900-1150 °C for 6h in the air.  
45  
46  
47  
48  
49  
50  
51  
52

### 53 *2.2 Characteristics*

54  
55  
56 The crystal structure and phase(s) of the specimens were analyzed using X-ray  
57  
58 diffraction (CuK $\alpha$ 1, 1.54059 Å, Model X'Pert PRO, PANalytical, Almelo, Holland).  
59  
60

The diffraction patterns were taken at room temperature in the range of 10 °-80 ° by step scans. The bulk density was determined by the Archimedes' method and the theoretical density was obtained by the following equation:

$$\rho_{th} = \frac{\omega_1 + \omega_2}{\omega_1/\rho_1 + \omega_2/\rho_2} \quad (1)$$

where  $\omega_1$ ,  $\omega_2$ , and  $\rho_1$ ,  $\rho_2$  are the mass fractions and theoretical density of  $\text{Sr}_2\text{V}_2\text{O}_7$  and  $\text{Sr}_3(\text{VO}_4)_2$ , respectively.

The surface morphologies of the sintered samples were observed by scanning electron microscope (FE-SEM, Model S4800, Hitachi, Japan). The relative permittivity ( $\epsilon_r$ ) and quality factor ( $Q \times f$ ) of the samples were measured using a network analyzer (Model N5230A, Agilent Co., Palo Alto, America). The temperature coefficient of resonant frequency ( $\tau_f$ ) was measured by noting the temperature shift of the resonance scope in the temperature range of 25-85 °C using a temperature chamber (Delta 9039, Delta Design, San Diego, CA) and were calculated as follows:

$$\tau_f (\text{ppm}/^\circ\text{C}) = \frac{f_2 - f_1}{f_1(T_2 - T_1)} \times 10^6 \quad (2)$$

where,  $f_1$  and  $f_2$  represent resonant frequencies at temperatures  $T_1$  and  $T_2$ , respectively.

### 3. Results and discussion

In order to get a clear understanding of the chemical reaction happening within  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  system, thermal analysis was carried out. Fig. 1(a) shows the TG/DSC thermograph of the mixed precursor of the  $y = 0.2$  sample. Three endothermic peaks between 150 °C to 450 °C were observed in the DSC curve, accompanied by a total mass loss of nearly 8% on the TGA curve. These three peaks, located at 200 °C, 225 °C and 370 °C correspond to the gradual decomposition of  $\text{NH}_4\text{VO}_3$  into  $\text{V}_2\text{O}_5$  and  $\text{NH}_3$



1  
2  
3  
4 with the first as the primary decomposition process. A broad exothermic peak around  
5  
6 527 °C can be related to the chemical reaction of  $V_2O_5$  with  $SrCO_3$  to form  $Sr_2V_2O_7$   
7  
8 and/or  $Sr_3V_2O_8$  with mass loss of nearly 8% due to the release of carbon dioxide. The  
9  
10 endothermic peak at 880 °C is associated with the complete decomposition of  $SrCO_3$ .  
11  
12 **Fig. 1(b)** shows the XRD pattern of the  $y = 0.2$  sample sintered at 860 and 960 °C. A  
13  
14 peak belonging to  $SrCO_3$  is visible at 860 °C, which disappeared at 960 °C, hence  
15  
16 confirming the thermal analysis.  
17  
18  
19  
20  
21

22 **Fig. 2(a)** illustrates the XRD patterns of  $Sr_{3-y}V_2O_{8-y}$  ( $y = 0.2-0.8$ ) ceramics sintered  
23  
24 at 950 °C. Within the range of  $0.2 \leq y \leq 0.8$ , only two main crystalline phases,  $Sr_2V_2O_7$   
25  
26 with a space group P-1 (No. 2) and  $Sr_3(VO_4)_2$  were observed and the volume fraction  
27  
28 of  $Sr_2V_2O_7$  increased with increasing  $y$  value, as listed in **Table 1**, which was verified  
29  
30 based on the bi-phase Rietveld refinement. As representatives, **Figs. 2(b, c)** show the  
31  
32 refined XRD patterns with  $y = 0.2$  and  $y = 0.8$ . The reasonable reliability factors indicate  
33  
34 that a mixed-phase of  $Sr_3(VO_4)_2$  and  $Sr_2V_2O_7$  were obtained in all samples. Additionally,  
35  
36 **Fig. 2(d)** shows the change of relative density as a function of  $y$  value and phase fraction  
37  
38 of  $Sr_2V_2O_7$  calculated from refinement. All the sintered  $Sr_{3-y}V_2O_{8-y}$  samples exhibited  
39  
40 a relative density of over 95% and an upward trend with an increase in  $y$  value,  
41  
42 indicating that the increment of  $V_2O_5$  content facilitates densification of  $Sr_{3-y}V_2O_{8-y}$ .  
43  
44 The phase content of  $Sr_2V_2O_7$  increased from 20.47% to 81.31%, which is very close  
45  
46 to the theoretical values (17.88% to 77.7%) obtained from the nominal formula  $Sr_{3-  
47  
48  
49  
50  
51  
52  
53  
54  
55  
56  
57  
58  
59  
60$

**Fig. 3(a-d)** present the SEM images of  $Sr_{3-y}V_2O_{8-y}$  ( $y = 0.2-0.8$ ) sintered at their

1  
2  
3  
4 optimum temperatures. Following the high relative density (over 95%, Table 1), all the  
5  
6 samples show well-densified microstructures. It can be seen that two different shapes  
7  
8 of grains (round and columnar grains) coexisted in the samples in the composition range  
9  
10 studied. Fig. 3(e, f) presented the elemental content in different grains (spot 1 and 2)  
11  
12 captured using EDS. The Sr/V ratio of the columnar phases is approximately 1.52,  
13  
14 which is close to the composition of  $\text{Sr}_3\text{V}_2\text{O}_8$ , while Sr/V ratio for the round phase is  
15  
16 around 1.01, corresponding to  $\text{Sr}_2\text{V}_2\text{O}_7$  phase. The EDS results confirmed that the  
17  
18 round-like grains were  $\text{Sr}_2\text{V}_2\text{O}_7$  phase and the columnar-like grains were  $\text{Sr}_3\text{V}_2\text{O}_8$  phase.  
19  
20  
21  
22  
23

24  
25 The microwave dielectric properties ( $\epsilon_r$ ,  $Q \times f$ , and  $\tau_f$ ) of  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ( $y = 0.2-0.8$ )  
26  
27 ceramics exhibited a downward trend with increasing  $y$  value as shown in Fig. 4.  
28  
29 Particularly, the  $\tau_f$  value of the  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ceramics decreased from +48.7 ppm/°C to -  
30  
31 20.1 ppm/°C.  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  composite having  $y = 0.6$  and sintered at 950 °C demonstrated  
32  
33 a near-zero  $\tau_f$  of -1.1 ppm/°C, along with  $\epsilon_r$  of 9.8 and quality factor  $Q \times f$  of 24,120  
34  
35 GHz. According to the empirical Lichtenecker mixing rule for a two-phase composite,  
36  
37 the effective  $\epsilon_r$ ,  $Q \times f$ , and  $\tau_f$  values can be theoretically estimated by the following  
38  
39 equations [28]:  
40  
41  
42  
43  
44

$$\epsilon^n = V_1 \epsilon_1^n + V_2 \epsilon_2^n \quad (-1 \leq n \leq 1) \quad (3)$$

$$\tau_f = v_1 \tau_{f1} + v_2 \tau_{f2} \quad (4)$$

$$\frac{1}{Q} = \frac{v_1}{Q_1} + \frac{v_2}{Q_2} \quad (5)$$

45  
46 where  $\epsilon_1$  and  $\epsilon_2$  are the respective permittivities of  $\text{Sr}_3(\text{VO}_4)_2$  and  $\text{Sr}_2\text{V}_2\text{O}_7$  phase;  $\tau_{f1}$   
47  
48 and  $\tau_{f2}$  are the  $\tau_f$  values of the pure  $\text{Sr}_3(\text{VO}_4)_2$  and  $\text{Sr}_2\text{V}_2\text{O}_7$  phase,  $V_1$  and  $V_2$  ( $V_1 + V_2 =$   
49  
50 1) are the volume fractions of the corresponding phases. And  $n = 1$  or  $-1$  correspond to  
51  
52  
53  
54  
55  
56  
57  
58  
59  
60

1  
2  
3  
4 the parallel and series mixing law, respectively. When  $n$  approaches 0, Eq. (3) becomes  
5  
6 logarithmic, usually used for randomly distributed composites:  
7

$$\ln \varepsilon = V_1 \ln \varepsilon_1 + V_2 \ln \varepsilon_2 \quad (6)$$

8  
9  
10  
11 As shown in Fig. 4(a), the measured values of  $\varepsilon_r$  for  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ( $y = 0.0-1.0$ ) composites  
12  
13 are matched with values calculated using equations of parallel or series mixing law, and  
14  
15 Eq. (6). This indicates that the measured values of  $\varepsilon_r$  follow the logarithmic mixing law  
16  
17 with the respective volume fraction. The theoretical  $Q \times f$  and  $\tau_f$  values of  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ( $y$   
18  
19 = 0.2-0.8) are calculated using the Eq. (4) and (5) and shown in Figs. 4(b, c). The  
20  
21 measured  $Q \times f$  and  $\tau_f$  values were in agreement with the theoretical values, confirming  
22  
23 that the dielectric properties can be conveniently and precisely tailored by this method.  
24  
25  
26  
27  
28  
29

30 The low sintering temperature (950 °C) of sample with  $y = 0.6$  enables its potential  
31  
32 application in LTCC technology. To evaluate the chemical compatibility with silver,  
33  
34 cofiring was carried out between the  $y = 0.6$  and 20 wt.% Ag powders at 950 °C for 2  
35  
36 h. As shown, XRD pattern recorded on the cofired sample only exhibits peaks of silver  
37  
38 (ICDD No. 87-0717),  $\text{Sr}_3\text{V}_2\text{O}_8$ , and  $\text{Sr}_2\text{V}_2\text{O}_7$ . In addition, backscattered electron image  
39  
40 (BEI) shows distinguish grains with different element contrasts and the bright grains  
41  
42 were verified as silver by EDS analysis. These results suggest that the present ceramics  
43  
44 have a good chemical compatibility with Ag electrode, rendering their potential use in  
45  
46  
47  
48  
49  
50  
51 LTCC technology.  
52

#### 53 4. Conclusions

54  
55  
56 To tailor the temperature coefficient of resonance frequency and lower the  
57  
58 sintering temperature of  $\text{Sr}_3\text{V}_2\text{O}_8$ , in-situ composite formation through modified Sr:V  
59  
60

1  
2  
3  
4 ratio was proposed and a series of  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  were prepared. Successful reduction in  
5  
6 sintering temperature was achieved from 1150 °C to 950 °C, rendering their future  
7  
8 possible application in LTCC technology. Microwave dielectric properties can also be  
9  
10 tuned by varying the Sr:V ratio. In particular, a composition with  $y = 0.6$  sintered at 950  
11  
12 °C possessed a near-zero  $\tau_f$  of -1.1 ppm/°C, along with  $\epsilon_r$  of 9.8 and quality factor  $Q \times f$   
13  
14 of 24,120 GHz. This work paves the way for  $\text{Sr}_3(\text{VO}_4)_2$  ceramics to utilize in multilayer  
15  
16  
17  
18  
19 electronic devices.

20  
21  
22  
23  
24  
25  
26  
27  
28  
29  
30  
31  
32  
33  
34  
35  
36  
37  
38  
39  
40  
41  
42  
43  
44  
45  
46  
47  
48  
49  
50  
51  
52  
53  
54  
55  
56  
57  
58  
59  
60

For Peer Review

## Acknowledgments

This work was supported by the Natural Science Foundation of Guangxi Zhuang Autonomous Region (No 2018GXNSFAA281253).

For Peer Review

## References

- [1] Sebastian MT, Jantunen H, Low loss dielectric materials for LTCC applications: a review. *Int. Mater. Rev.* 2008; 53: 57-90.
- [2] Song XQ, Du K, Li J, Muhammad R, Lu WZ, Wang XC, et al. Lattice structures and microwave dielectric properties of novel low-permittivity  $Ba_{1-x}Sr_xZnSi_3O_8$  ceramics. *J. Am. Ceram. Soc.* 2019; 112: 178-181.
- [3] Zhou D, Pang LX, Wang DW, Qi ZM, Reaney IM, High quality factor, ultralow sintering temperature  $Li_6B_4O_9$  microwave dielectric ceramics with ultralow density for antenna substrates. *ACS Sustainable Chem. Eng.* 2018; 6: 11138-11143.
- [4] Zhang SB, Shi LW, Zhang LY, Zhu HY, Xia WS, Synthesis and microwave dielectric properties of new high quality  $Mg_2NdNbO_6$  ceramics. *J. Am. Ceram. Soc.* 2018; 101: 1014-1019.
- [5] George S, Sebastian MT, Synthesis and microwave dielectric properties of novel Temperature Stable High Q  $Li_2ATi_3O_8$  (A=Mg, Zn) Ceramics. *J. Am. Ceram. Soc.* 2010; 30: 2585-2592.
- [6] Li CC, Xiang HC, Xu MY, Tang Y, Fang L,  $Li_2AGeO_4$  (A = Zn, Mg): Two novel low-permittivity microwave dielectric ceramics with olivine structure. *J. Eur. Ceram. Soc.* 2018; 38: 1524-1528.
- [7] Shi F, Yang J, Liu Q, Qi ZM, Sun H, Crystal structure, lattice vibrational characteristic, and dielectric property of  $Nd(Mg_{1/2}Sn_{1/2})O_3$  ceramic. *Mater. Chem. Phys.* 2017; 200: 9-15.
- [8] Li CC, Yin CZ, Chen JQ, Xiang HC, Tang Y, Fang L, Crystal structure and dielectric properties of germanate melilites  $Ba_2MGe_2O_7$  (M= Mg and Zn) with low permittivity. *J. Eur. Ceram. Soc.* 2018; 38: 5246-5251.
- [9] Liu B, Hu CC, Huang YH, Bafroeei HB, Song KX, Crystal structure, infrared reflectivity spectra and microwave dielectric properties of  $CaAl_2O_4$  ceramics with low permittivity. *J. Alloys Compd.* 2019; 791: 1033-1037.
- [10] Ullah A, Liu H, Hao H, Iqbal J, Yao Z, Cao M, Influence of  $TiO_2$  additive on sintering temperature and microwave dielectric properties of  $Mg_{0.90}Ni_{0.1}SiO_3$  ceramics. *J. Eur. Ceram. Soc.* 2017; 37: 3045-3049.
- [11] Shamiryan D, Abell T, Iacopi F, Maex K, Low-K dielectric materials. 7th Philadelphia, PA: Materialstoday; 2004.
- [12] Bian JJ, Sun XQ, Xie YR, Structural evolution, sintering behavior and microwave dielectric properties of  $Al_{(1-x)}(Si_{0.5}Zn_{0.5})_xPO_4$  ceramics. *J. Eur. Ceram. Soc.* 2019; 39: 4139-4143.
- [13] Chen D, Luo F, Gao L, Zhou WC, Zhu DM, Dielectric and microwave absorption properties of divalent-doped  $Na_3Zr_2Si_2PO_{12}$  ceramics. *J. Eur. Ceram. Soc.* 2018; 38: 4440-4445.
- [14] Xiang HC, Li CC, Tang Y, Fang L, Two novel ultralow temperature firing microwave dielectric ceramics  $LiMVO_6$  (M = Mo, W) and their chemical compatibility with metal electrodes. *J. Eur. Ceram. Soc.* 2017; 37: 3959-3963.
- [15] Wang Y, Zuo RZ, Zhang C, Zhang J, Zhang TW, Low-temperature-fired  $ReVO_4$  (Re = La, Ce) microwave dielectric ceramics. *J. Am. Ceram. Soc.* 2015; 98: 1-4.
- [16] Yin CZ, Li CC, Yang GJ, Fang L, Yuan YH, Shu LL, et al.  $NaCa_4V_5O_{17}$ : A low-firing microwave dielectric ceramic with low permittivity and chemical compatibility with silver

- 1  
2  
3 for LTCC applications. *J. Eur. Ceram. Soc.* 2020; 40: 386-390.
- 4 [17] Zhou D, Pang LX, Wang DW, Reaney M, BiVO<sub>4</sub> based high k microwave dielectric  
5 materials: a review. *J. Mater. Chem. C.* 2018; 6: 9290-9313.
- 6 [18] Zhou D, Guo D, Li WB, Pang LX, Yao X, Wang DW, et.al. Novel temperature stable high-  
7  $\epsilon_r$  microwave dielectrics in the Bi<sub>2</sub>O<sub>3</sub>-TiO<sub>2</sub>-V<sub>2</sub>O<sub>5</sub> system. *J. Mater. Chem. C.* 2016; 4: 5357-  
8 5362.
- 9 [19] Umemura R, Ogawa H, Ohsato H, Kan A, Yokoi A, Microwave dielectric properties of  
10 low-temperature sintered Mg<sub>3</sub>(VO<sub>4</sub>)<sub>2</sub> ceramic. *J. Eur. Ceram. Soc.* 2005; 25: 2865-2870.
- 11 [20] Umemura R, Ogawa H, Yokoi A, Ohsato H, Kan A, Low-temperature sintering-microwave  
12 dielectric property relations in Ba<sub>3</sub>(VO<sub>4</sub>)<sub>2</sub> ceramic. *J. Alloys Compd.* 2006; 424: 388-393.
- 13 [21] Cheng K, Li CC, Yin CZ, Tang Y, Sun YH, Fang L, Effects of Sr<sup>2+</sup> substitution on the  
14 crystal structure, raman spectra, bond valence and microwave dielectric properties of Ba<sub>3-x</sub>Sr<sub>x</sub>(VO<sub>4</sub>)<sub>2</sub>  
15 solid solutions. *J. Eur. Ceram. Soc.* 2019; 39: 3738-3743.
- 16 [22] Song XQ, Du K, Li J, Lan XK, Lu WZ, Wang XH, et al. Low-fired fluoride microwave  
17 dielectric ceramics with low dielectric loss. *Ceram. Int.* 45 2019 279-286.
- 18 [23] Guo HH, Zhou D, Pang LX, Qi ZM, Microwave dielectric properties of low firing  
19 temperature stable scheelite structured (Ca, Bi) (Mo, V)O<sub>4</sub> solid solution ceramics for  
20 LTCC applications. *J. Eur. Ceram. Soc.* 2019; 39: 2365-2373.
- 21 [24] Li WB, Zhou D, Xi HH, Pang LX, Yao X, Alford N, Structure, infrared reflectivity and  
22 microwave dielectric properties of (Na<sub>0.5</sub>La<sub>0.5</sub>)MoO<sub>4</sub>-(Na<sub>0.5</sub>Bi<sub>0.5</sub>)MoO<sub>4</sub> ceramics. *J. Am.*  
23 *Ceram. Soc.* 2016; 99: 2083-2088.
- 24 [25] Pang LX, Zhou D, Wang DW, Zhao JX, Liu WG, Yue ZX, et al. Temperature stable  
25 K<sub>0.5</sub>(Nd<sub>1-x</sub>Bi<sub>x</sub>)<sub>0.5</sub>MoO<sub>4</sub> microwave dielectrics ceramics with ultra-low sintering temperature.  
26 *J. Am. Ceram. Soc.* 2018; 101: 1806-1810.
- 27 [26] Jesse J, Brown JR, Phase equilibria in the system SrO-CdO-V<sub>2</sub>O<sub>5</sub>. *J. Am. Ceram. Soc.* 1972;  
28 55: 500-503.
- 29 [27] Joung MR, Kim JS, Song ME, Nahm S, Paik JH, Formation process and microwave  
30 dielectric properties of the R<sub>2</sub>V<sub>2</sub>O<sub>7</sub> (R = Ba, Sr, and Ca) ceramics. *J. Am. Ceram. Soc.* 2009;  
31 92: 3092-3094.
- 32 [28] Fukuda K, Kitoh R, Awai I, Microwave characteristics of TiO<sub>2</sub>-Bi<sub>2</sub>O<sub>3</sub> dielectric resonator,  
33 *Jpn. J. Appl. Phys.* 1993; 32: 4584-4588.
- 34  
35  
36  
37  
38  
39  
40  
41  
42  
43  
44  
45  
46  
47  
48  
49  
50  
51  
52  
53  
54  
55  
56  
57  
58  
59  
60

**Table 1** Comparison of calculated and theoretical values, sintering temperature, and microwave dielectric properties of  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ceramics

$y$	The volume fraction of $\text{Sr}_2\text{V}_2\text{O}_7$		Theoretical density ( $\text{g}/\text{cm}^3$ )	Relative density (%)	Optimum sintering temperature ( $^{\circ}\text{C}$ )	Dielectric properties		
	Calculation from Fullprof (%)	Theoretical Values (%)				$\epsilon_r$	$Q \times f$ (GHz)	$\tau_f$ (ppm/ $^{\circ}\text{C}$ )
0.2	20.47	17.88	4.39	96.36	1000	11.8	36,400	48.7
0.4	37.19	36.70	4.31	97.21	1000	10.6	34,960	20.6
0.6	57.48	56.51	4.24	98.11	950	9.8	27,550	-1.1
0.8	81.31	77.67	4.14	98.55	950	9.4	24,100	-20.1

For Peer Review



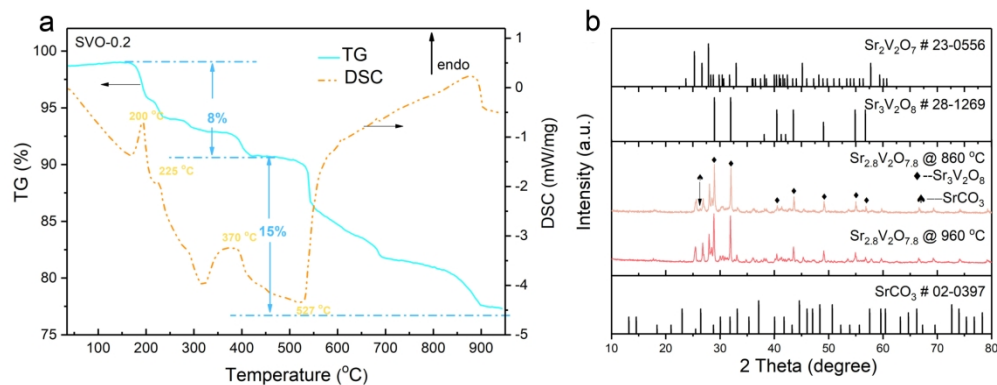


Figure 1 (a) TG/DSC analysis of the  $y = 0.2$  sample, (b) XRD patterns of  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ( $y = 0.2$ ) sintered at 860 °C and 960 °C.

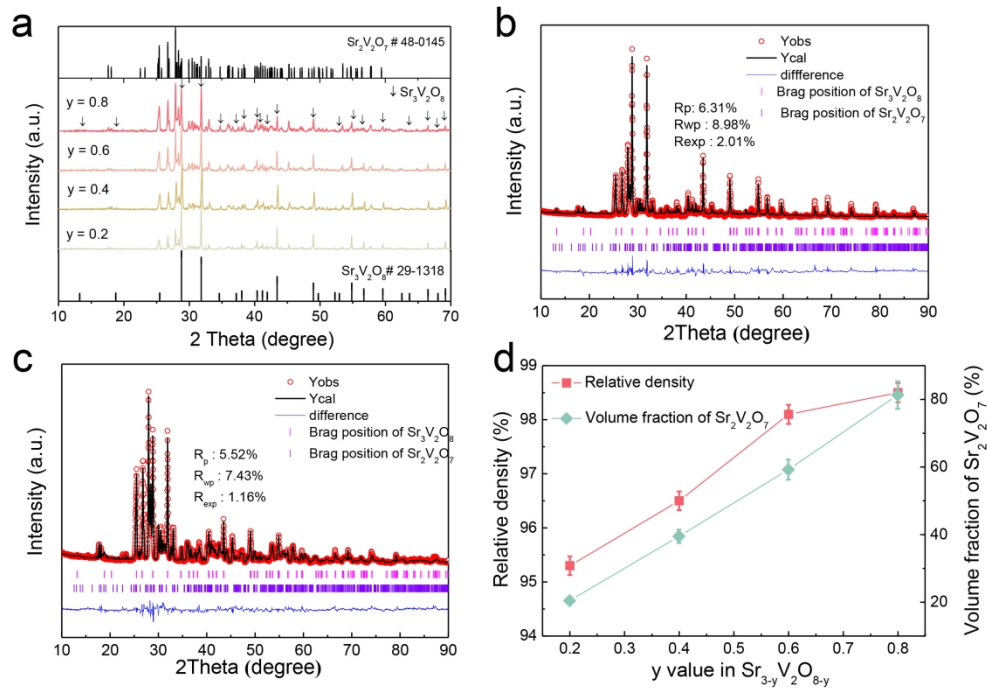


Figure 2 (a) XRD patterns of the  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ( $y = 0.2, 0.4, 0.6,$  and  $0.8$ ) sintered at optimum temperature, (b) Rietveld refinement profiles for  $y = 0.2$ , and (c) for  $y = 0.8$  and (d) change of phase fraction of  $\text{Sr}_2\text{V}_2\text{O}_7$  calculated from refinement.

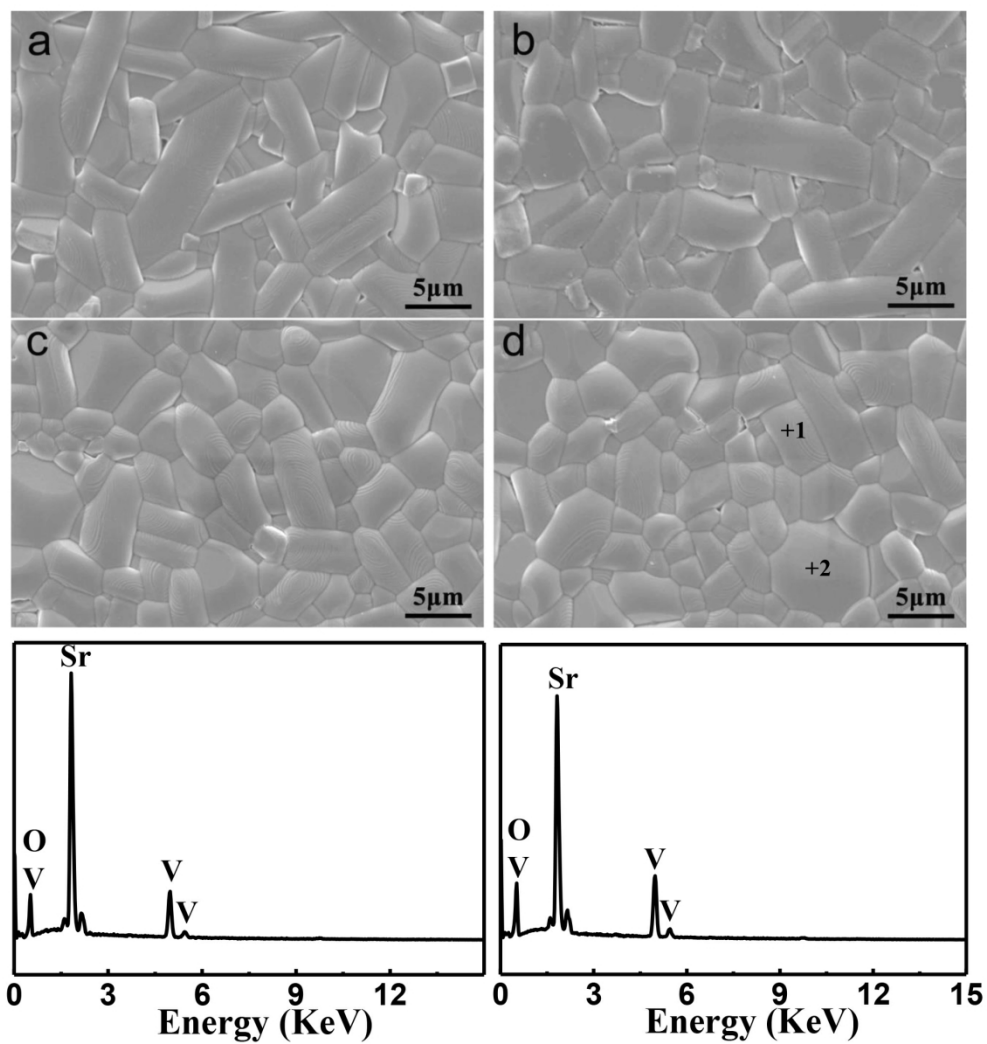


Figure 3 SEM images recorded on the polished and thermally etched surfaces of  $\text{Sr}_3\text{-yV}_2\text{O}_{8\text{-y}}$  ceramics: (a)  $y = 0.2$ , (b)  $y = 0.4$ , (c)  $y = 0.6$ , (d)  $y = 0.8$ ; (e) and (f) EDS for spot 1 and 2, respectively.

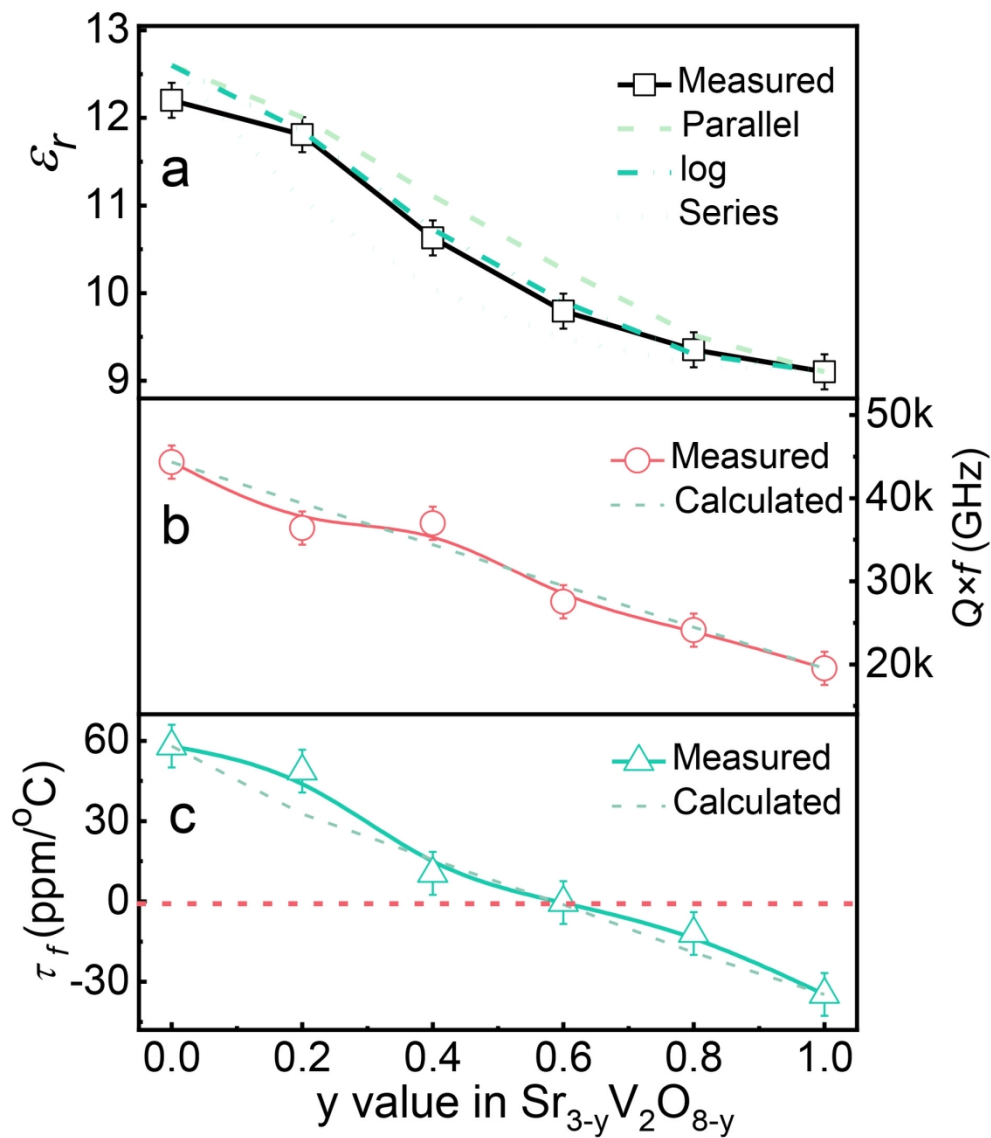


Fig. 4 Variations in microwave dielectric properties as a function of  $y$  in the  $\text{Sr}_{3-y}\text{V}_2\text{O}_{8-y}$  ceramics; the corresponding calculated values are also given for comparison.

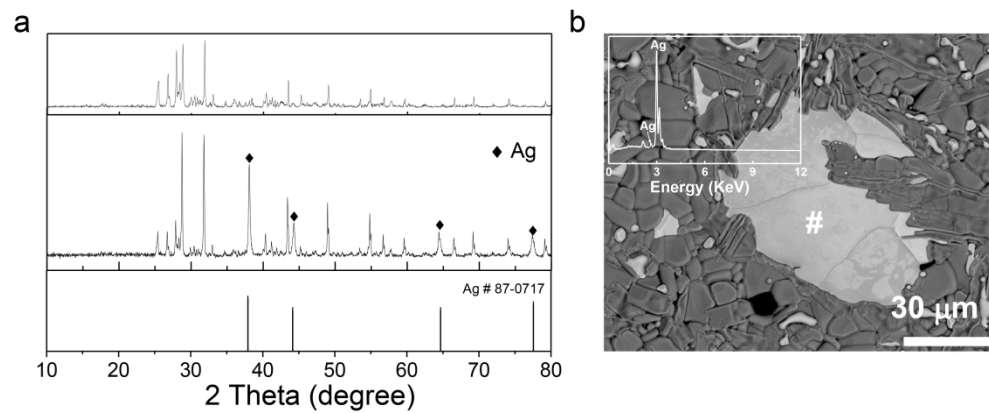


Figure 5 (a) XRD patterns and (b) SEM micrograph of  $\text{Sr}_{2.4}\text{V}_2\text{O}_{7.4}$  + 20 wt.% Ag powders at 950 °C for 2 h (EDS analysis of Ag is shown in the inset of Fig. 5(b)).